

### DESCRIPTION

The MP3221 is a 1.2MHz frequency, 6-pin TSOT23 current mode step up converter intended for small, low power applications. The device can step up three-cell alkaline, NiCd, and NiMH batteries, or a single-cell Li-on battery up to 6V. It is capable of delivering 1A output current at 5V with a supply voltage of 3V.

The MP3221 provides the internal soft start and compensation to minimize the external component count and help producing a compact solution. It integrates a FAULT driver for external PMOS to disconnect the output from input when the part shuts down or in output short circuit condition. This disconnect feature allows the output to be completely discharged, thus allowing the part to draw less than 1µA off current in shutdown mode.

The MP3221 is available in a small 6-pin TSOT23 package.

### FEATURES

- Integrated 88mΩ Power MOSFET
- 270µA Quiescent Current
- 2.5V to 6V Input Voltage
- 3V to 6V Output Voltage
- 1.2MHz Fixed Switching Frequency
- Internal 2.7A Switch Current Limit
- Integrated Input Disconnect Driver
- Internal Soft Start and Compensation
- True Output Disconnect from Input
- Under Voltage Lockout
- Short-Circuit Protection
- Over-Temperature Protection
- Available in a 6-Pin TSOT23-6 Package

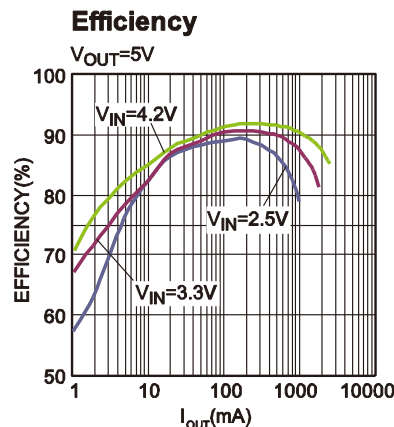
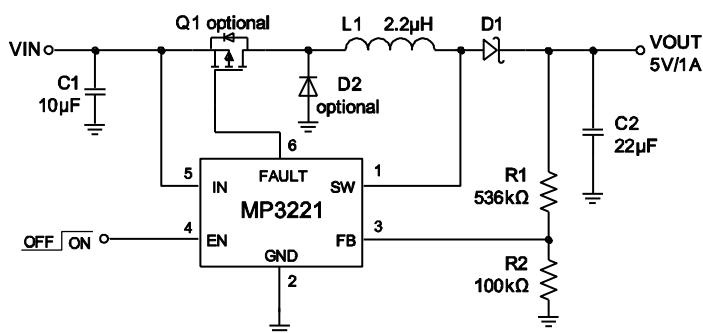
### APPLICATIONS

- Single-Cell Lion Battery or Three-Cell Alkaline, NiCd, or NiMH Battery Based Products
- Portable Media Players
- Wireless Peripherals
- Tablets and Smart Phones

All MPS parts are lead-free and adhere to the RoHS directive. For MPS green status, please visit MPS website under Products, Quality Assurance page.

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### TYPICAL APPLICATION

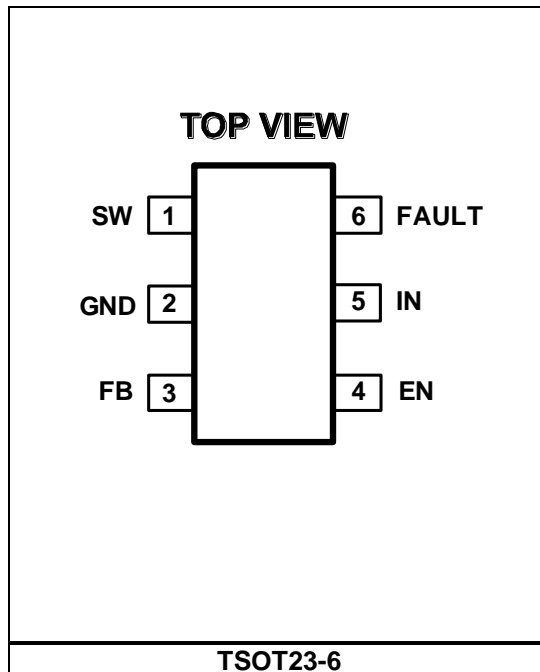


**ORDERING INFORMATION**

| Part Number* | Package  | Top Marking |
|--------------|----------|-------------|
| MP3221GJ     | TSOT23-6 | AFB         |

\* For Tape & Reel, add suffix -Z (e.g. MP3221GJ-Z);

**PACKAGE REFERENCE**



**ABSOLUTE MAXIMUM RATINGS <sup>(1)</sup>**

|   |  |
|---|--|
| $V_{SW}$ .....  | -0.3V(-2V for <10nS)to +8V(9V for <10nS) |
| All Other Pins.....   | -0.3V to +6.5 V                          |
| Continuous Power Dissipation( $T_A = +25^{\circ}C$ ) <sup>(2)</sup> | 0.56W                                    |
| Junction Temperature .....  | 150°C                                    |
| Lead Temperature .....  | 260°C                                    |
| Storage Temperature.....  | -65°C to +150°C                          |

**Recommended Operating Conditions <sup>(3)</sup>**

|                                     |                 |
|-------------------------------------|-----------------|
| Supply Voltage $V_{IN}$ .....       | 2.5V to 6V      |
| Output Voltage $V_{OUT}$ .....      | 3V to 6V        |
| Operating Junction Temp.( $T_J$ ).. | -40°C to +125°C |

|  |               |               |      |
|--|---------------|---------------|------|
| <b>Thermal Resistance <sup>(4)</sup></b> | $\theta_{JA}$ | $\theta_{JC}$ |      |
| TSOT23-6 .....                           | 220           | 110           | °C/W |

**Notes:**

- 1) Exceeding these ratings may damage the device.
- 2) The maximum allowable power dissipation is a function of the maximum junction temperature  $T_J$  (MAX), the junction-to-ambient thermal resistance  $\theta_{JA}$ , and the ambient temperature  $T_A$ . The maximum allowable continuous power dissipation at any ambient temperature is calculated by  $P_D$  (MAX) =  $(T_J$  (MAX)- $T_A$ )/ $\theta_{JA}$ . Exceeding the maximum allowable power dissipation will cause excessive die temperature, and the regulator will go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
- 3) The device is not guaranteed to function outside of its operating conditions.
- 4) Measured on JESD51-7, 4-layer PCB.

## ELECTRICAL CHARACTERISTICS

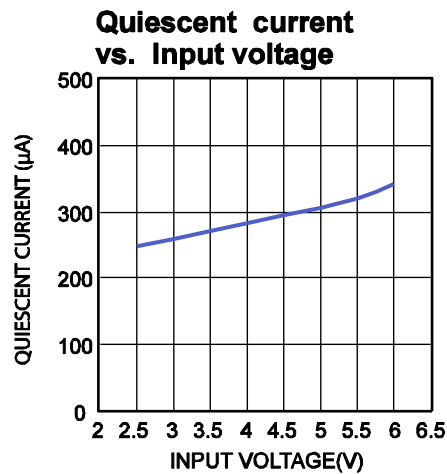
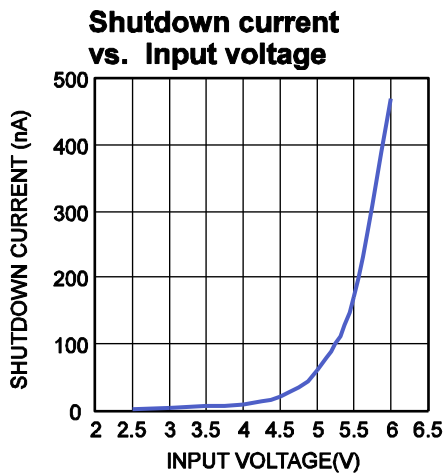
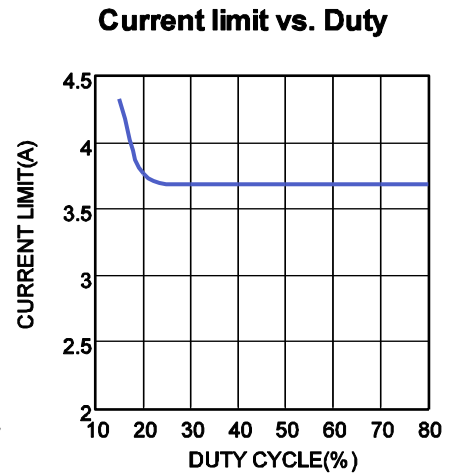
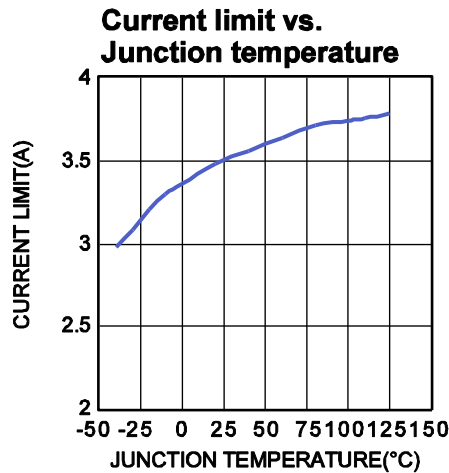
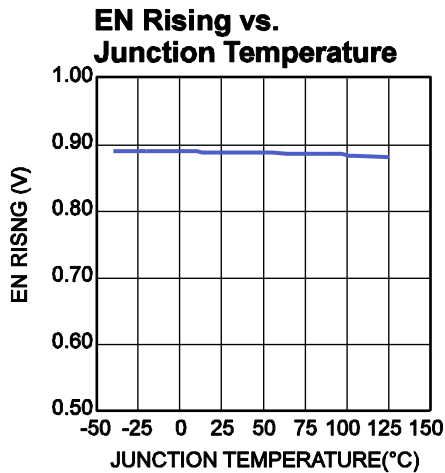
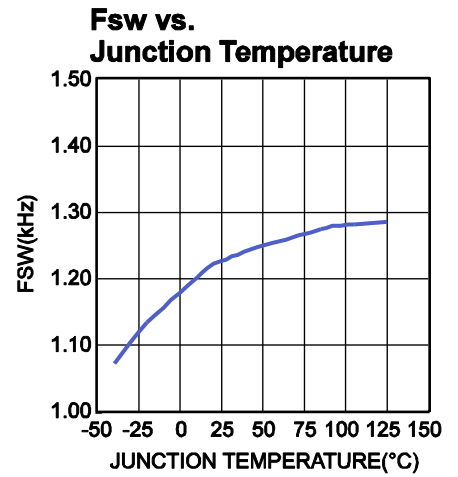
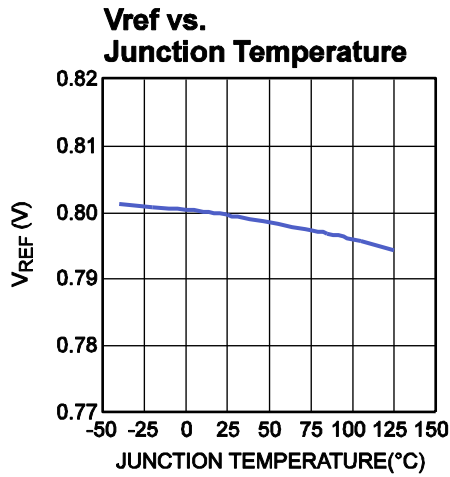
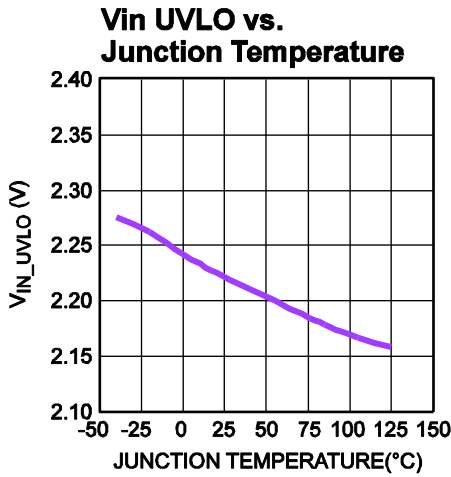
$V_{IN} = V_{EN} = 3.3V$ ,  $T_A = 25^{\circ}C$ , unless otherwise noted.

| Parameter                                  | Symbol          | Condition                          | Min   | Typ   | Max   | Units       |
|--|-----------------|------------------------------------|-------|-------|-------|-------------|
| Operating Input Voltage                    | $V_{IN}$        |                                    | 2.5   |       | 6     | V           |
| IN Under Voltage Lockout                   | $V_{UVLO}$      | $V_{IN}$ Rising                    | 2.0   | 2.2   | 2.4   | V           |
| IN Under Voltage Lockout Hysteresis        |                 |                                    |       | 225   |       | mV          |
| Shutdown Current                           | $I_{SD}$        | $V_{EN} = 0V$                      |       |       | 0.15  | $\mu A$     |
| Quiescent Current                          |                 | $V_{FB} = 0.85V$ ,<br>No Switching |       | 270   |       | $\mu A$     |
| Switching Frequency                        | $f_{SW}$        |                                    | 1     | 1.2   | 1.4   | MHz         |
| Minimum On time <sup>(5)</sup>             | $T_{ON,MIN}$    |                                    |       | 80    |       | ns          |
| Maximum Duty Cycle                         | $D_{MAX}$       | $V_{FB} = 0.6V$                    | 90    |       |       | %           |
| EN Input High Voltage                      |                 | $V_{EN,H}$                         | 1.3   |       |       | V           |
| EN Input Low Voltage                       |                 | $V_{EN,L}$                         |       |       | 0.5   | V           |
| EN Input Bias Current                      |                 | $V_{EN} = 5V$                      |       | 4     |       | $\mu A$     |
| FB Voltage                                 | $V_{FB}$        | $V_{EN} = 5V$                      | 0.780 | 0.796 | 0.812 | V           |
| FB Input Bias Current                      |                 | $V_{FB} = 0.82V$                   | -50   | -10   |       | nA          |
| FAULT Detection Threshold Voltage          | $V_{FB-AULT}$   | Step-up Converter Fails            | 110   | 150   | 185   | mV          |
| FAULT Pull Down Current                    | $I_{FAULT}$     |                                    | 85    | 115   | 145   | $\mu A$     |
| FAULT Pin Output Low Voltage               |                 | $V_{FB}=0.6V$ , $I=30\mu A$        |       |       | 0.3   | V           |
| SW On Resistance                           | $R_{DS(ON)}$    |                                    |       | 88    |       | m $\Omega$  |
| SW Current Limit                           |                 | Duty Cycle = 40%                   | 2.7   | 3.7   | 5.2   | A           |
| SW Leakage                                 |                 | $V_{SW} = 5V$                      |       |       | 1     | $\mu A$     |
| Thermal Shutdown <sup>(5)</sup>            | $T_{SHDN\_TH}$  |                                    |       | 150   |       | $^{\circ}C$ |
| Thermal Shutdown Hysteresis <sup>(5)</sup> | $T_{SHDN\_HYS}$ |                                    |       | 20    |       | $^{\circ}C$ |

**Notes:**

5) Guaranteed by engineering sample characterization. not production tested.

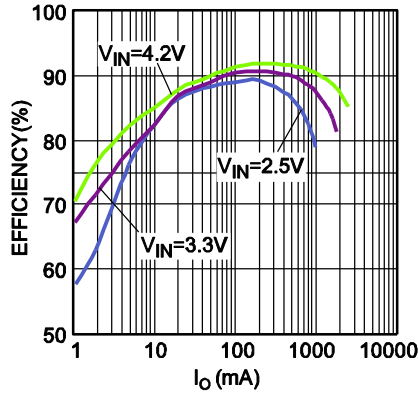
**TYPICAL CHARACTERISTICS**



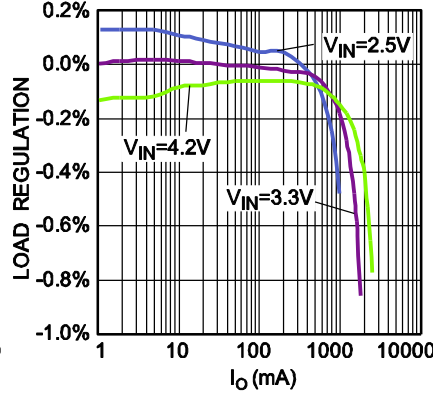
## TYPICAL PERFORMANCE CHARACTERISTICS

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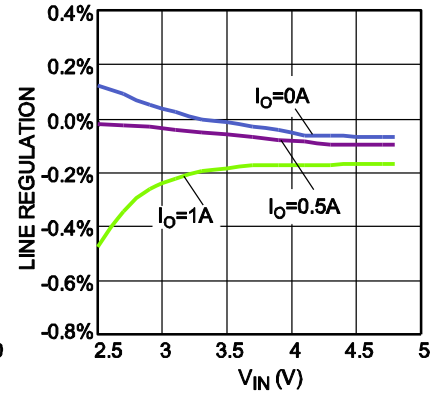
**Efficiency**



**Load regulation**

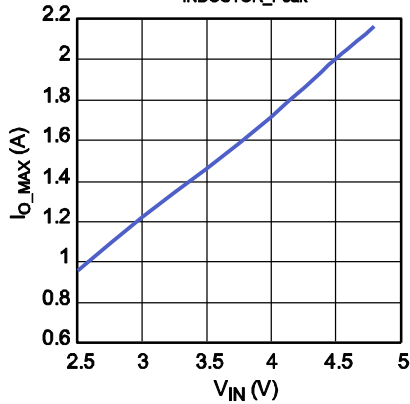


**Line regulation**

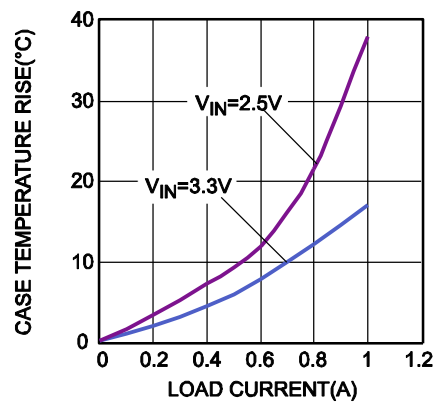


**Max. Output Current Vs. Vin Voltage**

Tested with  $I_{INDUCTOR\_Peak} = 2.7A$

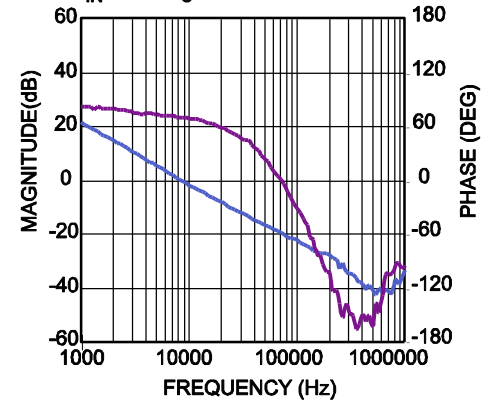


**Case temperature Rise vs. Load current**



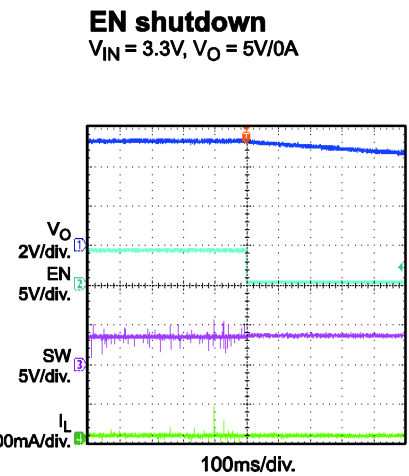
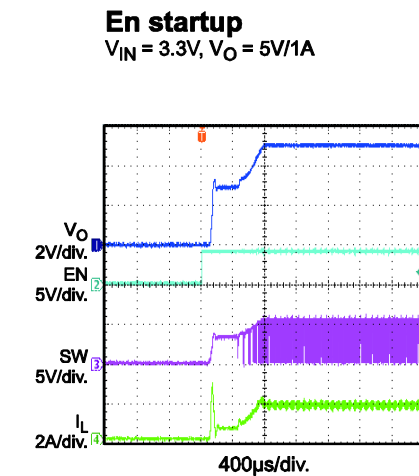
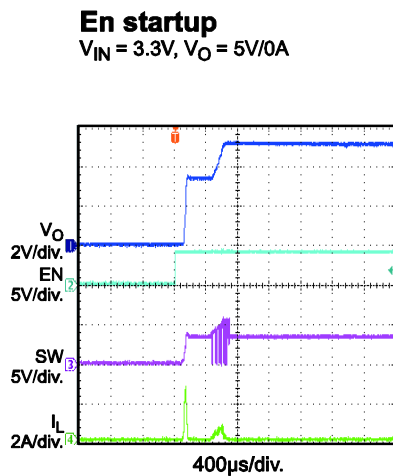
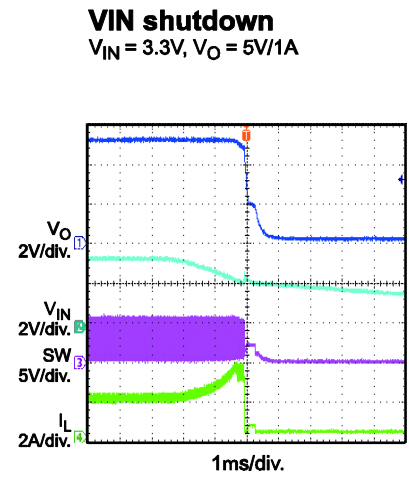
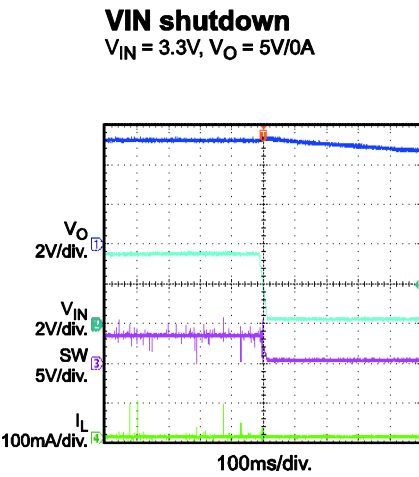
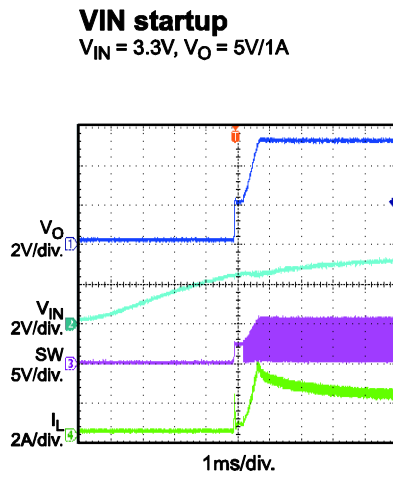
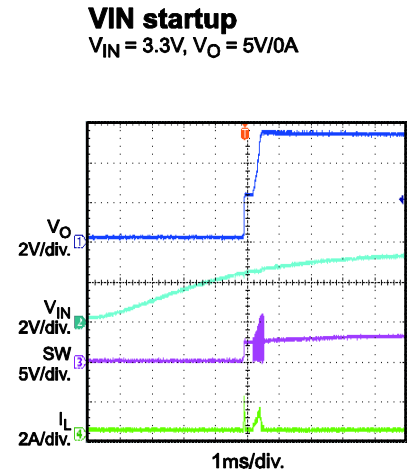
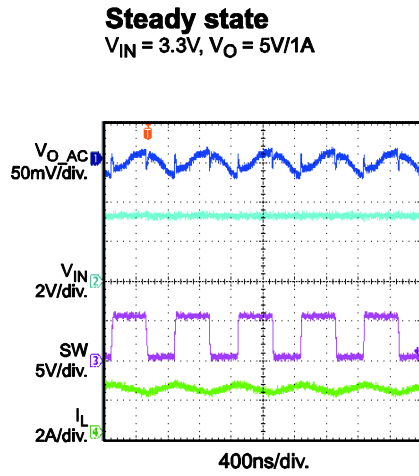
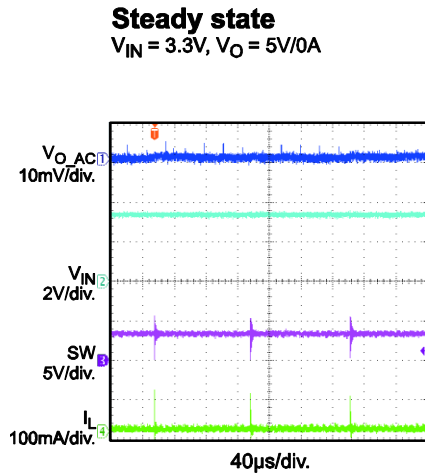
**Magnitude and phase vs. Frequency**

$V_{IN} = 3.3V$ ,  $V_O = 5V/1A$



## TYPICAL PERFORMANCE CHARACTERISTICS (continued)

$V_{IN} = 3.3V$ ,  $V_{OUT} = 5V$ ,  $L = 2.2\mu H$ ,  $T_A = 25^\circ C$ , unless otherwise noted.

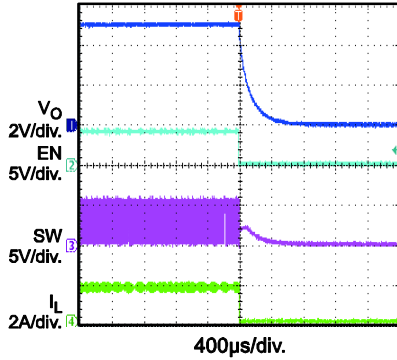


**TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

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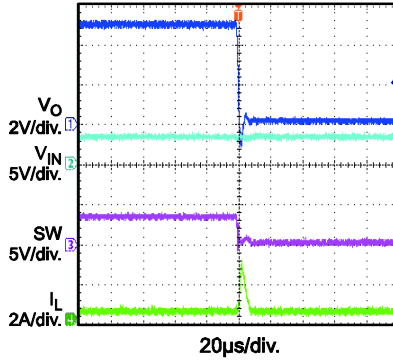
**EN shutdown**

$V_{IN} = 3.3V$ ,  $V_O = 5V/1A$



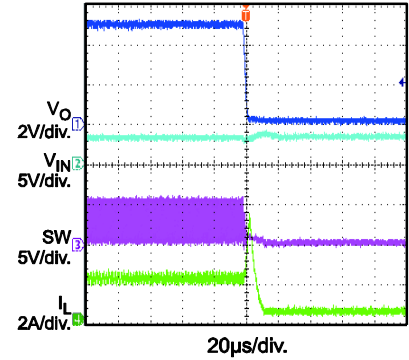
**SCP entry**

$V_{IN} = 3.3V$ ,  $V_O = 5V/0A$  to short



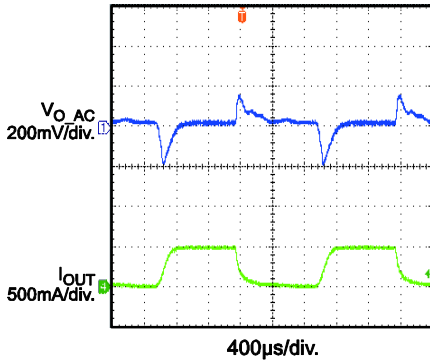
**SCP entry**

$V_{IN} = 3.3V$ ,  $V_O = 5V/1A$  to short



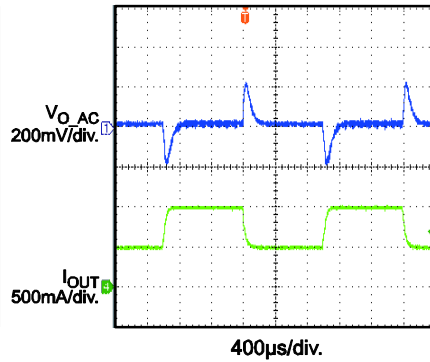
**Load transient**

$V_{IN} = 3.3V$ ,  $V_O = 5V$ ,  
 $I_O = 0A \rightarrow 0.5A$  | ramp =  $10mA/\mu s$



**Load transient**

$V_{IN} = 3.3V$ ,  $V_O = 5V$ ,  
 $I_O = 0.5A \rightarrow 1A$  | ramp =  $10mA/\mu s$



## PIN FUNCTIONS

| Pin # | Name                 | Description  |
|-------|----------------------|--|
| 1     | SW                   | Power Switch Output. SW is the drain of the internal MOSFET switch. Connect the power inductor and output rectifier to SW.   |
| 2     | GND                  | Ground.  |
| 3     | FB                   | Feedback Input. The FB voltage is 0.796V. Connect a resistor divider to FB.  |
| 4     | EN                   | Regulator On/Off Control Input. A high input at EN turns on the converter, and a low input turns it off. When not used, connect EN to the input supply for automatic startup.  |
| 5     | IN                   | Input Supply Pin. Must be locally bypassed.  |
| 6     | FAULT <sup>(6)</sup> | Fault Disconnection Switch Gate Output. When the system starts up normally, this pin smoothly turns on the external PMOS. When the MP3221 is disabled or in fault condition, the external PMOS is turned off to disconnect the input and output. |

**Notes:**

6) Fault pin only can protect circuits in SCP condition after parts startup.



**FUNCTION DIAGRAM**

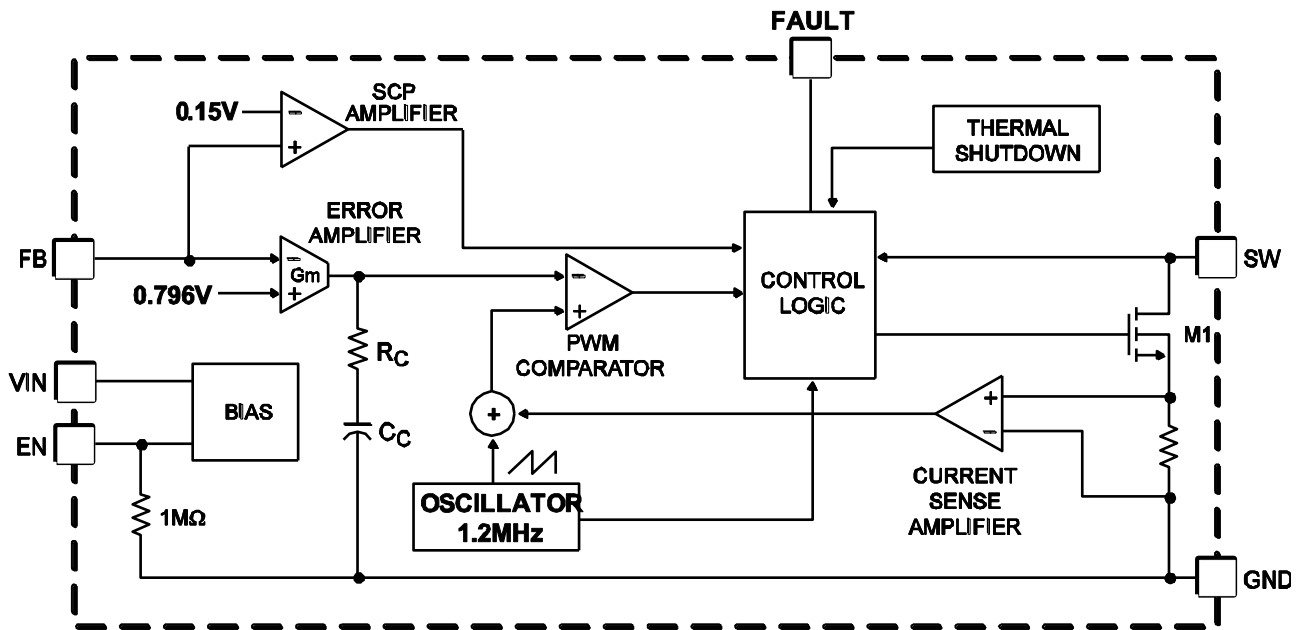


Figure 1: Functional Block Diagram

## OPERATION

The MP3221 uses a constant frequency, peak current mode boost regulator architecture to regulate voltage at the feedback pin.

The operation of the MP3221 can be understood by referring to the block diagram of Figure 1. At the start of each oscillating cycle the MOSFET is turned on through the control circuitry. To prevent sub-harmonic oscillations at duty cycles greater than 50%, a stabilizing ramp is added to the output of the current sense amplifier and the result is fed into the negative input of the PWM comparator. When this voltage equals the output voltage of the error amplifier the power MOSFET is turned off.

The voltage at the output of the error amplifier is an amplified version of the difference between the band gap reference voltage and the feedback voltage. In this way the peak current level keeps the output in regulation. If the feedback voltage starts to drop, the output of the error amplifier increases, which results in more current flow through the power MOSFET, thus increasing the power delivered to the output.

### Start-Up Sequence

When MP3221 is enabled, the FAULT pin drives the external Fault Disconnection PMOS to turn on slowly. After the FAULT pin voltage drops to  $V_{IN} - 1.8V$ , parts works and checks all fault condition, if they are all in function. MP3221 will boost the output voltage to the expect voltage controlled by the internal soft start.

### Protection Operation

MP3221 has short-circuit protection function by turning off the external PMOS after parts startup. When FB voltage drops to 150mV due to the SCP occurs or any other factors, FAULT pin voltage will pull up quickly by MP3221's internal logic. Then the PMOS will disconnect to isolate input and output. This function won't act before  $V_{FAULT}$  drop to  $V_{IN} - 1.8V$ , MP3221 will also check other safety limits including UVLO and OTP.

### $V_{OUT}$ Disconnect from $V_{IN}$

To prevent the battery from discharging, the FAULT pin of MP3221 will drive and turn off the external PMOS to disconnect  $V_{OUT}$  from the battery when the part is in shut down mode. It also can disconnect output from input while the output is shorted to GND, thus help protect battery and circuit.

## APPLICATION INFORMATION

### COMPONENT SELECTION

#### Input Capacitor Selection

Low ESR input capacitors reduce input switching noise and reduce the peak current drawn from the battery. Ceramic capacitors are good choice for input decoupling and it should be located as close as possible to the IN and GND pin. Add a ceramic capacitor larger than 10µF close to the IC.

#### Selecting the Output Capacitor

The output capacitor requires a minimum capacitance value of 22µF at the programmed output voltage to ensure stability over the full operating range. A higher capacitance value may be required to lower the output ripple and also the transient response. Low ESR capacitors, such as X5R- or X7R-type ceramic capacitors, are recommended. Assuming that the ESR is zero, estimate the minimum output capacitance to support the ripple in the CCM mode as:

$$C_o \geq \frac{I_o \times (V_{OUT} + V_F - V_{IN(MIN)})}{f_s \times (V_{OUT} + V_F) \times \Delta V}$$

Where:

$V_{OUT}$  = output voltage

$V_{IN(MIN)}$  = Minimum Input voltage

$V_F$  = Diode Forward voltage

$I_o$  = Output current

$f_s$  = Switching frequency

$\Delta V$  = Acceptable output ripple

#### Selecting the Inductor

The inductor is required to force the higher output voltage while being driven by the input voltage. A larger value inductor results in less ripple current that results in lower peak inductor current, reducing stress on the internal N-Channel switch. However, the larger value inductor has a larger physical size, higher series resistance, and/or lower saturation current.

A 2.2µH inductor is recommended for most applications. However, a more exact inductance

value can be calculated. A good rule of thumb is to allow the peak-to-peak ripple current to be approximately 30-50% of the maximum input current. Make sure that the peak inductor current is below 75% of the current limit at the operating duty cycle to prevent loss of regulation due to the current limit. Also make sure that the inductor does not saturate under the worst-case load transient and startup conditions. Calculate the required inductance value by the equation:

$$L = \frac{V_{IN} \times (V_{OUT} + V_F - V_{IN})}{(V_{OUT} + V_F) \times f_{SW} \times \Delta I}$$

$$I_{IN(MAX)} = \frac{V_{OUT} \times I_{LOAD(MAX)}}{V_{IN} \times \eta}$$

$$\Delta I = (30\% - 50\%) I_{IN(MAX)}$$

Where  $I_{LOAD(MAX)}$  is the maximum load current,  $\Delta I$  is the peak-to-peak inductor ripple current, and  $\eta$  is efficiency.

#### Selecting the Diode

The output rectifier diode supplies current to the inductor when the internal MOSFET is off. To reduce power loss due to diode forward voltage and recovery current, use a Schottky diode with the MP3221. The diode should be rated for a reverse voltage equal to or higher than the output voltage. The average current rating must be higher than the maximum load current, and the peak current rating must be higher than the peak inductor current.

#### Selecting the PMOS

The MP3221 is capable of driving P-Channel power MOSFETS to disconnect input and output. The critical parameter selection of a MOSFET are:

1. Maximum drain to source voltage,  $V_{DS(MAX)}$
2. Maximum current  $I_{D(MAX)}$
3. On-resistance  $R_{DS(ON)}$
4. Total gate charge,  $Q_G$ .

Ideally, the off-state voltage across the MOSFET is equal to the input voltage.  $V_{DS(MAX)}$

should be greater than 1.5 times of the input voltage.

The maximum current through the power MOSFET happens when the input voltage is minimum and the output power is maximum.

The maximum Average current is the input current. The  $I_{D(max)}$  should be greater than 1.5 times the input current.

The on resistance of the MOSFET determines the conduction loss. It is smaller, it is better.

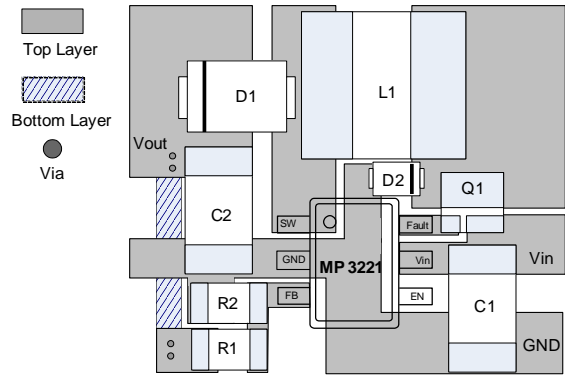
The Qg of PMOS should be well designed to avoid the triggering of SCP protection during start-up. Since  $V_{GATE}$  is pulled down with  $115\mu A$  through the Fault pin, the SCP function is enabled after  $V_{GATE}$  drops to  $V_{IN}-1.8V$ . With higher Qg, the time to pull  $V_{GATE}$  from  $V_{IN}$  to  $V_{IN}-1.8V$  is longer, and output voltage can be charged to higher voltage. If Qg is low,  $V_{GATE}$  will be pulled down quickly, and feedback  $V_{FB}$  is still lower than 150mV when  $V_{GATE}$  drops to  $V_{IN}-1.8V$ , then SCP function may be triggered and the start-up will fail.

A 3.3nF cap between gate-to-source of PMOS is recommended if  $V_{OUT}$  can not rise up before  $V_{FAULT}$  drops to  $V_{IN}-1.8V$  due to large output cap.

**PCB Layout Considerations**

Layout is important, especially for switching power supplies with high switching frequencies; poor layout results in reduced performance, EMI problems, resistive loss, and even system instability. Following the rules below can help ensure a stable layout design:

1. All components must be placed as close to the IC as possible. Keep the path between L1, D1,  $C_{OUT}$ , and IC-GND extremely short for minimal noise and ringing.
2.  $C_{IN}$  must be placed close to the IN pin for best decoupling.
3. All feedback components must be kept close to the FB pin to prevent noise injection on the FB pin trace.
4. The ground return of  $C_{IN}$  and  $C_{OUT}$  should be tied close to the GND pin.



**Figure 2: Layout**

**Notes:**

Refer to SCH on page 1.

**Design example**

Below is a design example following the application guidelines for the following Specifications:

**Table 1: Design Example**

|           |           |
|-----------|-----------|
| $V_{IN}$  | 2.5V-4.8V |
| $V_{OUT}$ | 5V        |
| $F_{SW}$  | 1.2MHz    |

The typical application circuit for  $V_{OUT} = 5V$  in Figure 3 shows the detailed application schematic, and is the basis for the typical performance and circuit waveforms. For more detailed device applications, please refer to the related Evaluation Board Datasheets.

**TYPICAL APPLICATION CIRCUITS**

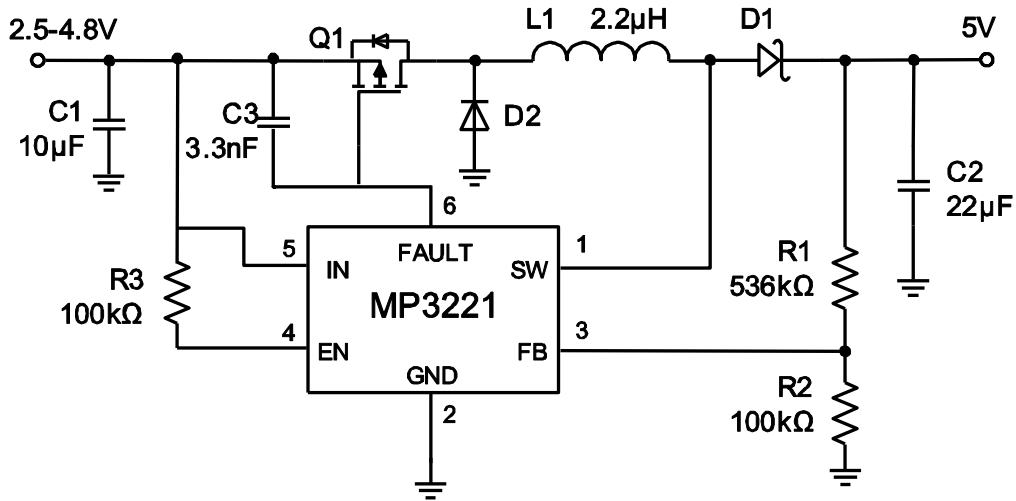


Figure 3:  $V_{IN}=2.5-4.8V$ ,  $V_{OUT}=5V/1A$ , with Input/Output Disconnection

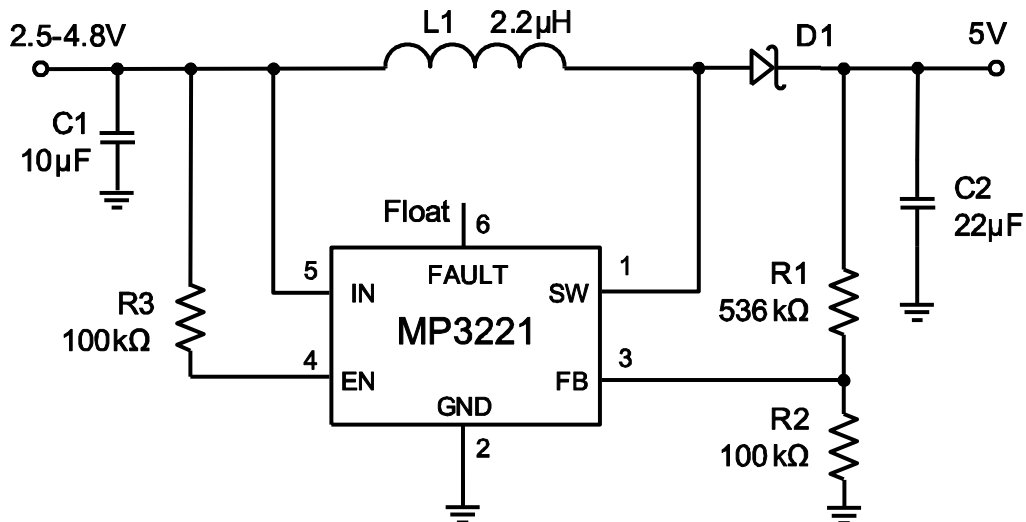
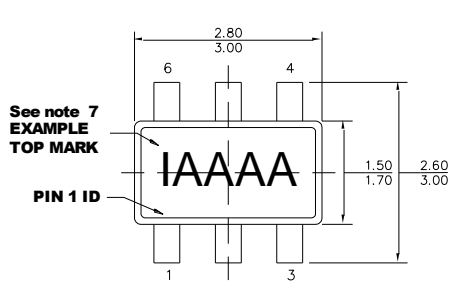


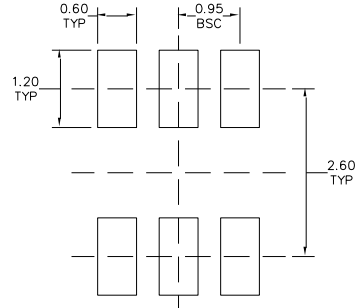
Figure 4:  $V_{IN}=2.5-4.8V$ ,  $V_{OUT}=5V/1A$ , without Input/Output Disconnection

**PACKAGE INFORMATION**

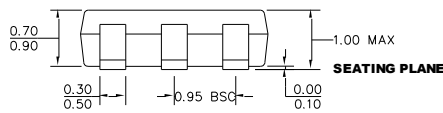
**TSOT23-6**



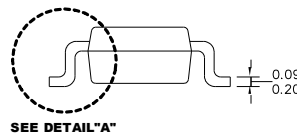
**TOP VIEW**



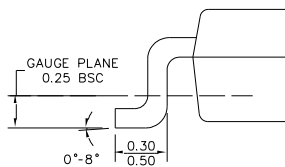
**RECOMMENDED LAND PATTERN**



**FRONT VIEW**



**SIDE VIEW**



**DETAIL "A"**

**NOTE:**

- 1) ALL DIMENSIONS ARE IN MILLIMETERS
- 2) PACKAGE LENGTH DOES NOT INCLUDE MOLD FLASH PROTRUSION OR GATE BURR
- 3) PACKAGE WIDTH DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION
- 4) LEAD COPLANARITY(BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.10 MILLIMETERS MAX
- 5) DRAWING CONFORMS TO JEDEC MO193, VARIATION AB
- 6) DRAWING IS NOT TO SCALE
- 7) PIN 1 IS LOWER LEFT PIN WHEN READING TOP MARK FROM LEFT TO RIGHT, (SEE EXAMPLE TOP MARK)

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